



5W MONO BRIDGE AMPLIFIER

TECHNOLOGY BI20II

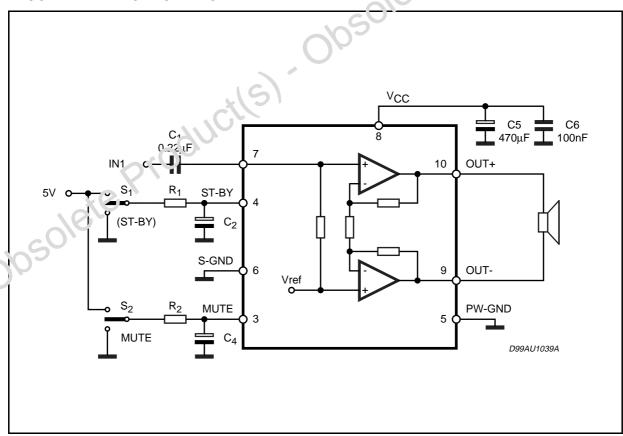
- WIDE SUPPLY VOLTAGE RANGE (3.5V-18V)
- MINIMUM EXTERNAL COMPONENTS
 - NO SVR CAPACITOR
 - NO BOOTSTRAP
 - NO BOUCHEROT CELLS
 - INTERNALLY FIXED GAIN
- STAND-BY & MUTE FUNCTIONS
- SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION

SIP10 ORDERING NUMBER: 1.7A 7266L

DESCRIPTION

The TDA7266L is a mono bridge amplifier specially designed for TV and Portable Radio applications.

BLOCK AND APPLICATION DIAGRAM



February 2001 1/7

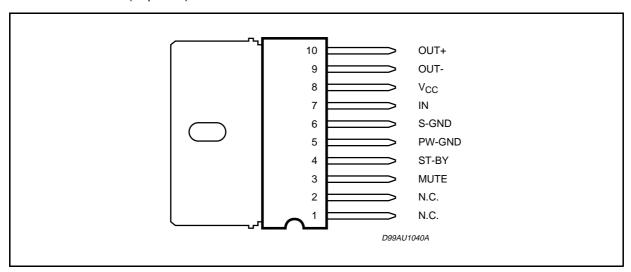
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	20	V
lo	Output Peak Current (internally limited)	2	Α
P _{tot}	Total Power Dissipation (T _{case} = 70°C)	10	W
Top	Operating Temperature	0 to 70	°C
T _{stg} , T _j	Storage and Junction Temperature	-40 to +150	°C

THERMAL DATA

Symbol	Description	Description Value	
R _{th j-case}	Thermal Resistance Junction to case	8	°C/W
R _{th j-amb}	Thermal Resistance Junction to ambient	70	°C/W

PIN CONNECTION (Top view)



ELECTRICAL CHARACTERISTICS (V_{CC} = 11V, R_L = 8Ω , f = 1kHz, T_{amb} = 25°C unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vcc	Supply Range		3.5	10	18	V
$I_{\mathbf{q}}$	Total Quiescent Current			35	50	mA
Vos	Output Offset Voltage				120	mV
Po	Output Power	THD = 10%	5.5	7		W
THD	Total Harmonic Distortion	$P_O = 1W$		0.05	0.2	%
		$P_0 = 0.1W$ to 2W f = 100Hz to 15kHz			1	%
SVR	Supply Voltage Rejection	f = 100Hz VR = 0.5V	40	50		dB
A _{MUTE}	Mute Attenuation		60	80		dB
T_W	Thermal Threshold			150		°C
G _V	Closed Loop Voltage Gain			32		dB
Ri	Input Resistance		31		33	ΚΩ
VT _{MUTE}	Mute Threshold	for $V_{CC} > 6.4V$; $V_{O} = -30dB$ for $V_{CC} < 6.4V$; $V_{O} = -30dB$	2.3 V _{CC} /2 -1	2.9 V _{CC} /2 -0.75	4.1 V _{CC} /2 -0.5	V

ELECTRICAL CHARACTERISTICS (Continued)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
VT _{ST-BY}	St-by Threshold		0.8	1.3	1.8	V
I _{ST-BY}	ST-BY current V6 = GND				100	μΑ
e _N	Total Output Noise Voltage	A curve f = 20Hz to 20kHz		150		μV

APPLICATION SUGGESTION

STAND-BY AND MUTE FUNCTIONS

(A) Microprocessor Application

In order to avoid annoying "Pop-Noise" during Turn-On/Off transients, it is necessary to guarantee the right St-by and mute signals sequence. It is quite simple to obtain this function using a microprocessor (Fig. 1 and 2).

At first St-by signal (from mP) goes high and the voltage across the St-by terminal (Pin 7) starts to increase exponentially. The external RC network is intended to turn-on slowly the biasing circuits of the amplifier, this to avoid "POP" and "CLICK" on the outputs.

When this voltage reaches the St-by threshold level, the amplifier is switched-on and the external capacitors in series to the input terminals (C3, C5) start to charge.

It's necessary to mantain the mute signal low until the capacitors are fully charged, this to avoid that the device goes in play mode causing a loud "Pop Noise" on the speakers.

A delay of 100-200ms between St-by and mute signals is suitable for a proper operation.

(B) Low Cost Application

In low cost applications where the μP is not present, the suggested circuit is shown in fig.3.

The St-by and mute terminals are tied together and they are connected to the supply line via an external voltage divider.

The device is switched-on/off from the supply line and the external capacitor C4 is intended to delay the St-by and mute threshold exceeding, avoiding "Popping" problems.

Figure 1: Microprocessor Driving Signals.

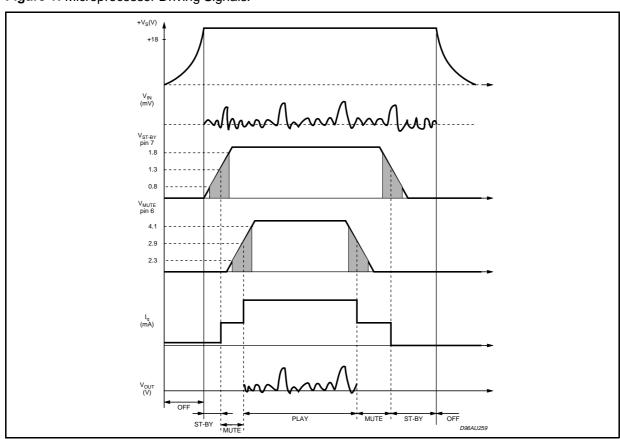
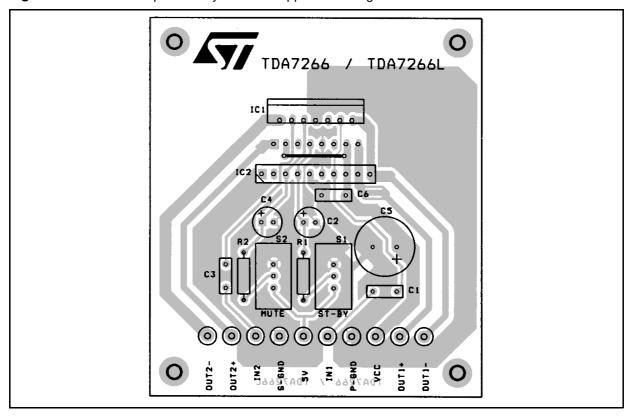


Figure 2: PCB and Component Layout of the Application Diagram



The PC board layout offers compatibility to TDA7266S, TDA7266, TDA7297, (the BTL power amplifiers in Multiwatt 15 package).

Figure 3: Distortion vs Output Power

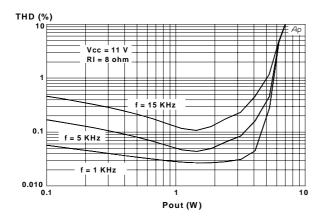


Figure 4: Distortion vs Output Power

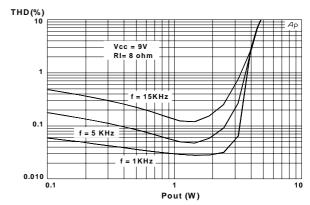


Figure 5: Distortion vs Frequency

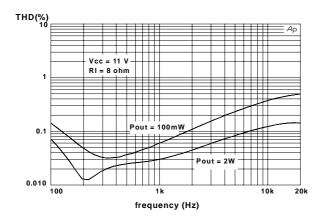


Figure 6: Gain vs Frequency

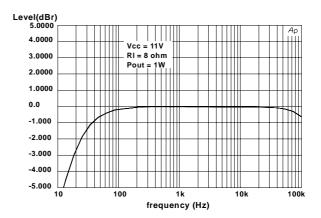


Figure 7: Mute Attenuation vs. V pin.6

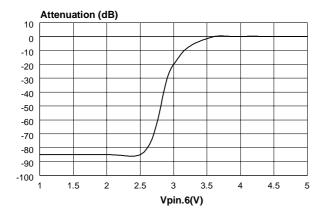


Figure 8: Stand-By Attenuation vs Vpin.7

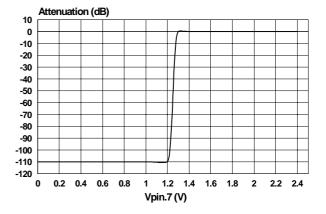
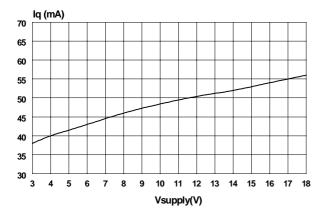


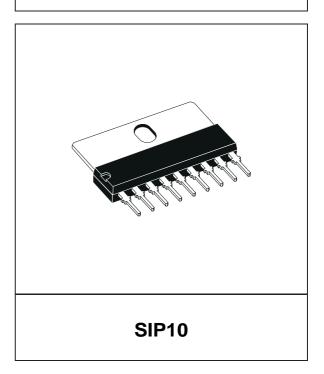
Figure 9: Quiescent Current vs. Supply Voltage

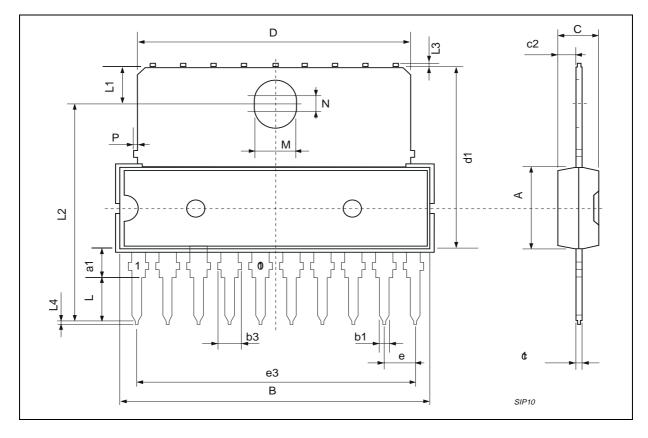


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DIM.	mm			inch			
DIN.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			7.1			0.280	
a1	2.7		3	0.106		0.118	
В			24.8			0.976	
b1		0.5			0.020		
b3	0.85		1.6	0.033		0.063	
С		3.3			0.130		
c1		0.43			0.017		
c2		1.32			0.052		
D			23.7			0.933	
d1		14.5			0.571		
е		2.54			0.100		
e3		22.86			0.900		
L	3.1			0.122			
L1		3			0.118		
L2		17.6			0.693		
L3			0.25			0.010	
L4			0.254			0.010	
М		3.2			0.126		
N		1			0.039		
Р			0.15			0.006	

OUTLINE AND MECHANICAL DATA





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